



### **QUADRUPLE 2-INPUT NAND GATES**

### Description

The 74LV00A provides provides four independent 2-input NAND gates with standard push-pull outputs. The device is designed for operation with a power supply range of 2.0V to 5.5V.

The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output preventing damaging current backflow when the device is powered down.

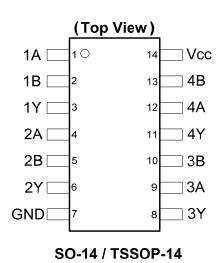
The gates perform the Boolean function:

$$Y = \overline{A \bullet B} \text{ or } Y = \overline{A} + \overline{B}$$

### Features

- Wide Supply Voltage Range from 2.0V to 5.5V
- Sinks or sources 12mA at V<sub>CC</sub> = 4.5V
- CMOS low power consumption
- IOFF Supports Partial -Power Down Operation
- Inputs or Outputs accept up to 5.5V
- Inputs can be driven by 3.3V or 5V allowing for voltage translation applications.
- Schmitt Trigger Action at All Inputs
- ESD Protection Tested per JESD 22
  - Exceeds 200-V Machine Model (A115)
  - Exceeds 2000-V Human Body Model (A114)
  - Exceeds 1000-V Charged Device Model (C101)
- Latch-Up Exceeds 100mA per JESD 78, Class I
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

### **Pin Assignments**



### Applications

- General Purpose Logic
- Power Down Signal Isolation
- Wide array of products such as:
  - PCs, networking, notebooks, ultrabooks, netbooks
  - Computer peripherals, hard drives, CD/DVD ROM
  - TV, DVD, DVR, set top box

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

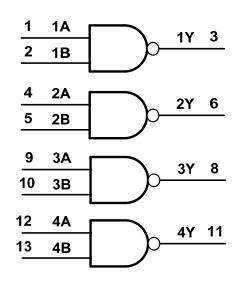
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## **Pin Descriptions**

Pin Number	Pin Name	Description
1	1A	Data Input
2	1B	Data Input
3	1Y	Data Output
4	2A	Data Input
5	2B	Data Input
6	2Y	Data Output
7	GND	Ground
8	3Y	Data Output
9	3A	Data Input
10	3B	Data Input
11	4Y	Data Output
12	4A	Data Input
13	4B	Data Input
14	Vcc	Supply Voltage

## Logic Diagram



## **Function Table**

Inp	Output	
Α	В	Y
Н	Н	L
L	Х	Н
Х	L	Н

## Absolute Maximum Ratings (Note 4) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
ESD MM	Machine Model ESD Protection	200	V
Vcc	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range note 4	-0.5 to +7.0	V
I <sub>IK</sub>	Input Clamp Current VI < 0V	-20	mA
I <sub>ОК</sub>	Output Clamp Current V <sub>O</sub> < -0V	-50	mA
lo	Continuous Output Current - 0.5V < V <sub>O</sub> V <sub>CC</sub> +0.5V	±25	mA
lcc	Continuous Current Through V <sub>CC</sub>	50	mA
I <sub>GND</sub>	Continuous Current Through GND	-50	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C
P <sub>TOT</sub>	Total Power Dissipation	500	mW

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



<b>Recommended Operating Conditions</b>	(Note 5) (@ $T_A$ = +25°C, unless otherwise specified.)
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Symbol	Parameter	Conditions	Min	Max	Unit
Vcc	Supply Voltage	—	2.0	5.5	V
VI	Input Voltage	—	0	5.5	V
Vo	Output Voltage	—	0	V <sub>CC</sub>	V
		2.0V	—	-50	mA
	Lligh Lovel Output Current	2.3V to 2.7V	—	-2	μA
IOH	High-Level Output Current	3.0V to 3.6V	—	-6	mA
		4.5V to 5.5V	—	-12	mA
	-	2.0V	—	50	μA
		2.3V to 2.7V	—	2	mA
IOL	Low-Level Output Current	3.0V to 3.6V	—	6	mA
		4.5V to 5.5V	—	12	mA
		2.3V to 2.7V	—	200	
Δt/ΔV	Input Transition Rise or Fall	3.0V to 3.6V	—	100	ns/V
		4.5V to 5.5V	_	20	
T <sub>A</sub>	Operating Free-Air Temperature	_	-40	+125	°C

Note: 5. Unused inputs should be held at V<sub>CC</sub> or Ground.

## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symphol	Deremeter	Test Canditians	N	T <sub>A</sub> = -40°C	C to +85°C	T <sub>A</sub> = -40°C	to +125°C	Unit
Symbol	Parameter	Test Conditions	Vcc	Min	Max	Min	Max	Unit
	High-Level Input	—	2.0V	1.5	—	1.5	—	
N		—	2.3V to 2.7V	V <sub>CC</sub> X 0.7	—	V <sub>CC</sub> X 0.7	—	V
VIH	Voltage	—	3.0V to 3.6V	V <sub>CC</sub> X 0.7	—	V <sub>CC</sub> X 0.7	—	
		—	4.5V to 5.5V	V <sub>CC</sub> X 0.7	—	V <sub>CC</sub> X 0.7	—	—
		—	2.0V	—	0.5	_	0.5	
N/	Low-Level Input	—	2.3V to 2.7V	—	V <sub>CC</sub> X 0.3	—	V <sub>CC</sub> X 0.3	V
VIL	Voltage	—	3.0V to 3.6V	—	V <sub>CC</sub> X 0.3	_	V <sub>CC</sub> X 0.3	
		—	4.5V to 5.5V	—	V <sub>CC</sub> X 0.3	—	V <sub>CC</sub> X 0.3	—
		I <sub>OH</sub> = -50µА	2.0V to 5.5V	V <sub>CC</sub> -0.1	—	V <sub>CC</sub> -0.1	—	
	High-Level	I <sub>OH</sub> = -2mA	2.3V	2.0	—	2.0	—	v
V <sub>OH</sub>	Output Voltage	I <sub>OH</sub> = -6mA	3.0V	2.48	—	2.48	—	v
		I <sub>OH</sub> = -12mA	4.5V	3.8	—	3.8	—	
		Ι <sub>ΟL</sub> = 50μΑ	2.0V to 5.5V	—	0.1	—	0.1	
	Low-Level	I <sub>OL</sub> = 2mA	2.3V	—	0.4	—	0.4	v
V <sub>OL</sub>	Output Voltage	I <sub>OL</sub> = 6mA	3.0V	—	0.44	—	0.44	v
		I <sub>OL</sub> = 12mA	4.5V	—	0.55	—	0.55	
I <sub>OFF</sub>	Power Down Leakage Current	$V_{I} \text{ or } V_{O} = 0 \text{ to } 5.5 \text{V}$	0V	—	5	—	5	μA
l <sub>l</sub>	Input Current	V <sub>I</sub> = GND or 5.5V	0 to 5.5V	_	±1	_	±1	μA
I <sub>CC</sub>	Supply Current	$V_1 = GND \text{ or } V_{CC}$ $I_0 = 0$	5.5V	_	20	_	20	μA



# **Switching Characteristics**

Symbol	Parameter	Test	V.	-	T <sub>A</sub> = +25°C	2	-40°C t	o +85°C	-40°C to	o +125°C	Unit
	Falameter	Conditions	Vcc	Min	Тур	Max	Min	Max	Min	Max	Unit
		Eiguro 1	2.5V ± 0.2V	_	7.1	12.9	1	15	1	16	
	t <sub>PD</sub> Propagation Delay A <sub>N</sub> to Y <sub>N</sub>	Figure 1 C <sub>L</sub> = 15pF Figure 1 C <sub>L</sub> = 50pF	3.3V ± 0.3V	_	5	7.9	1	9.5	1	10.5	ns
			5.0V ± 0.5V		3.6	5.5	1	6.5	1	7.5	
ι <sub>PD</sub>			2.5V ± 0.2V	_	9.6	16.6	1	20	1	21	
			3.3V ± 0.3V	_	6.9	11.4	1	13	1	14	ns
		CL = SOPF	5.0V ± 0.5V	_	4.9	7.5	1	8.5	1	9.5	

## **Operating Characteristics**

 $T_A = +25^{\circ}C$ 

	Parameter	Test Conditions	V <sub>cc</sub>	Тур	Unit
0	Power Dissipation	F = 10 MHz	3.3V	9.5	~ [
C <sub>pd</sub>	Capacitance per Gate	$C_L = 50 pF$	5.0V	11	pF

## **Noise Characteristics**

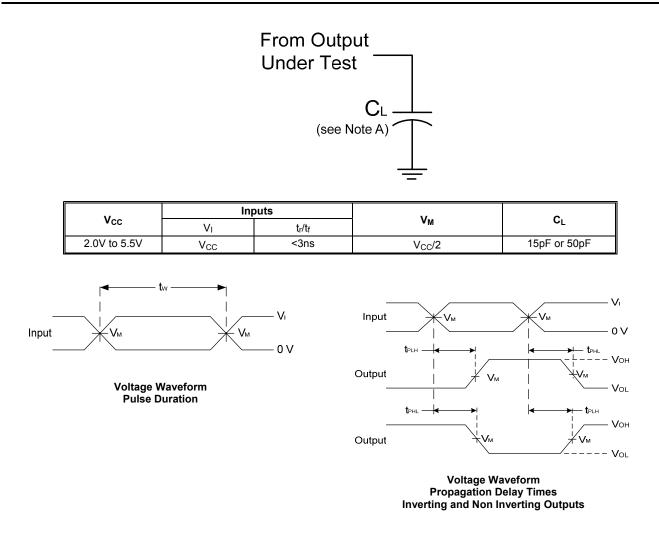
$V_{CC} = 3V, C_L =$	= 50pF, T <sub>A</sub> = +25°C				
Symbol	Parameter	Min	Тур	Max	Unit
V <sub>OL(p)</sub>	Quiet output, maximum dynamic V <sub>OL</sub>	—	0.2	0.8	V
V <sub>OL(V)</sub>	Quiet output, minimum dynamic V <sub>OL</sub>	—	-0.1	-0.8	V
V <sub>OH(V)</sub>	Quiet output, minimum dynamic V <sub>OH</sub>	—	3.1	—	V
V <sub>IH(D)</sub>	High Level dynamic input voltage	2.31		_	V
V <sub>IL(D)</sub>	Low Level dynamic input voltage	—		0.99	V

# **Package Characteristics**

Symbol	Parameter	Test Conditions	Vcc	Min	Тур	Max	Unit
Ci	Input Capacitance	$V_i = V_{CC} - or GND$	2.0 to 5.5V		3.3	10	pF



## **Parameter Measurement Information**

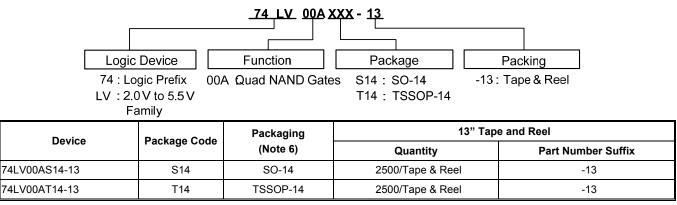


- Notes: A. Includes test lead and test apparatus capacitance.
  - B. All pulses are supplied at pulse repetition rate  $\leq$  10MHz
  - C. Inputs are measured separately one transition per measurement
  - D.  $t_{\text{PLH}}$  and  $t_{\text{PHL}}$  are the same as  $t_{\text{PD}}$

Figure 1 Load Circuit and Voltage Waveforms



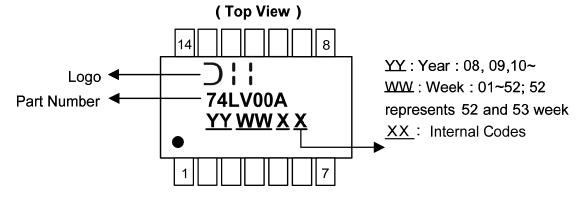
## **Ordering Information**



Note: 6. The taping orientation and tape details can be found at http://www.diodes.com/datasheets/ap02007.pdf

## **Marking Information**

### (1) SO14, TSSOP14



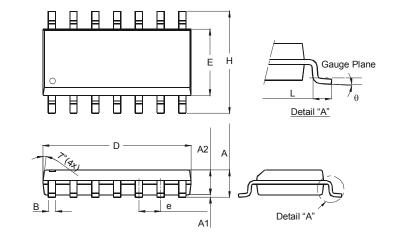
Part Number	Package
74LV00AS14	SO-14
74LV00AT14	TSSOP-14



## Package Outline Dimensions (All Dimensions in mm)

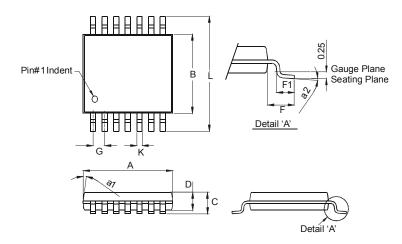
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

### Package Type: SO-14



	SO-14					
Dim	Min	Max				
Α	1.47	1.73				
A1	0.10	0.25				
A2	1.45	Тур				
в	0.33	0.51				
D	8.53	8.74				
ш	3.80	3.99				
e	1.27	Тур				
н	5.80	6.20				
L	0.38	1.27				
θ	0°	8°				
All Di	mensions	s in mm				

### Package Type: TSSOP-14



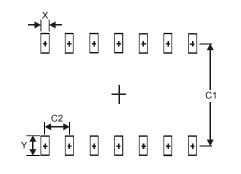
TSSOP-14		
Dim	Min	Max
a1	7° (4X)	
a2	0°	8°
Α	4.9	5.10
В	4.30	4.50
С	_	1.2
D	0.8	1.05
F	1.00 Typ	
F1	0.45	0.75
G	0.65 Typ	
κ	0.19	0.30
L	6.40 Typ	
All Dimensions in mm		



## **Suggested Pad Layout**

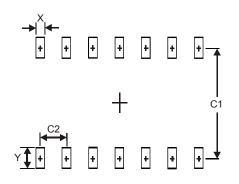
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

### Package Type: SO-14



Dimensions	Value (in mm)
Х	0.60
Y	1.50
C1	5.4
C2	1.27

Package Type: TSSOP-14



Dimensions	Value (in mm)
Х	0.45
Y	1.45
C1	5.9
C2	0.65



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